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#### Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

### Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	533MHz
Co-Processors/DSP	-
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	-
USB	USB 2.0 + PHY (2)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	672-LBGA
Supplier Device Package	672-LBGA (35x35)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8349zuajf

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

## NOTE

The information in this document is accurate for revision 3.x silicon and later (in other words, for orderable part numbers ending in A or B). For information on revision 1.1 silicon and earlier versions, see the *MPC8349E PowerQUICC II Pro Integrated Host Processor Hardware Specifications*.

See Section 22.1, "Part Numbers Fully Addressed by This Document," for silicon revision level determination.

# 1 Overview

This section provides a high-level overview of the device features. Figure 1 shows the major functional units within the MPC8349EA.



Figure 1. MPC8349EA Block Diagram

Major features of the device are as follows:

- Embedded PowerPC e300 processor core; operates at up to 667 MHz
  - High-performance, superscalar processor core
  - Floating-point, integer, load/store, system register, and branch processing units
  - 32-Kbyte instruction cache, 32-Kbyte data cache
  - Lockable portion of L1 cache
  - Dynamic power management
  - Software-compatible with the other Freescale processor families that implement Power Architecture technology

Figure 3 shows the undershoot and overshoot voltage of the PCI interface of the MPC8349EA for the 3.3-V signals, respectively.



Figure 3. Maximum AC Waveforms on PCI Interface for 3.3-V Signaling

# 2.1.3 Output Driver Characteristics

Table 3 provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

Driver Type	Output Impedance (Ω)	Supply Voltage
Local bus interface utilities signals	40	OV <sub>DD</sub> = 3.3 V
PCI signals (not including PCI output clocks)	25	
PCI output clocks (including PCI_SYNC_OUT)	40	
DDR signal	18	GV <sub>DD</sub> = 2.5 V
DDR2 signal	18 36 (half-strength mode)	GV <sub>DD</sub> = 1.8 V
TSEC/10/100 signals	40	LV <sub>DD</sub> = 2.5/3.3 V
DUART, system control, I <sup>2</sup> C, JTAG, USB	40	OV <sub>DD</sub> = 3.3 V
GPIO signals	40	OV <sub>DD</sub> = 3.3 V, LV <sub>DD</sub> = 2.5/3.3 V

Table 3. Output Drive Capability

# 2.2 **Power Sequencing**

This section details the power sequencing considerations for the MPC8349EA.

## 2.2.1 Power-Up Sequencing

MPC8349EA does not require the core supply voltage ( $V_{DD}$  and  $AV_{DD}$ ) and I/O supply voltages ( $GV_{DD}$ ,  $LV_{DD}$ , and  $OV_{DD}$ ) to be applied in any particular order. During the power ramp up, before the power

# 6.2.2 DDR and DDR2 SDRAM Output AC Timing Specifications

Table 20 shows the DDR and DDR2 output AC timing specifications.

## Table 20. DDR and DDR2 SDRAM Output AC Timing Specifications

At recommended operating conditions with  $\text{GV}_{\text{DD}}$  of (1.8 or 2.5 V) ± 5%.

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
ADDR/CMD/MODT output setup with respect to MCK	t <sub>DDKHAS</sub>			ns	3
400 MHz		1.95	—		
333 MHz		2.40	—		
266 MHz		3.15	—		
200 MHz		4.20	—		
ADDR/CMD/MODT output hold with respect to MCK	t <sub>DDKHAX</sub>			ns	3
400 MHz		1.95	—		
333 MHz		2.40	—		
266 MHz		3.15	—		
200 MHz		4.20	—		
MCS(n) output setup with respect to MCK	t <sub>DDKHCS</sub>			ns	3
400 MHz		1.95	—		
333 MHz		2.40	—		
266 MHz		3.15	—		
200 MHz		4.20	—		
MCS(n) output hold with respect to MCK	t <sub>DDKHCX</sub>			ns	3
400 MHz		1.95	—		
333 MHz		2.40	—		
266 MHz		3.15	—		
200 MHz		4.20	_		
MCK to MDQS Skew	t <sub>DDKHMH</sub>	-0.6	0.6	ns	4
MDQ/MECC/MDM output setup with respect to MDQS	t <sub>DDKHDS,</sub> t <sub>DDKLDS</sub>			ps	5
400 MHz		700	—		
333 MHz		775	—		
266 MHz		1100	—		
200 MHz		1200	—		
MDQ/MECC/MDM output hold with respect to MDQS	t <sub>DDKHDX,</sub> t <sub>DDKLDX</sub>			ps	5
400 MHz		700	—		
333 MHz		900	—		
266 MHz		1100	—		
200 MHz		1200	—		
MDQS preamble start	t <sub>DDKHMP</sub>	$-0.5\times t_{MCK}-0.6$	$-0.5\times t_{MCK}+0.6$	ns	6

Figure 7 shows the DDR SDRAM output timing diagram.



Figure 8 provides the AC test load for the DDR bus.



Figure 8. DDR AC Test Load

# 7 DUART

This section describes the DC and AC electrical specifications for the DUART interface of the MPC8349EA.

# 7.1 DUART DC Electrical Characteristics

Table 21 provides the DC electrical characteristics for the DUART interface of the MPC8349EA.

**Table 21. DUART DC Electrical Characteristics** 

Parameter	Symbol	Min	Мах	Unit
High-level input voltage	V <sub>IH</sub>	2	OV <sub>DD</sub> + 0.3	V
Low-level input voltage	V <sub>IL</sub>	-0.3	0.8	V
Input current (0.8 V $\leq$ V <sub>IN</sub> $\leq$ 2 V)	I <sub>IN</sub>	_	±5	μA

### Table 26. GMII Receive AC Timing Specifications (continued)

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V  $\pm$  10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
RX_CLK clock rise (20%–80%)	t <sub>GRXR</sub>		_	1.0	ns
RX_CLK clock fall time (80%-20%)	t <sub>GRXF</sub>	_		1.0	ns

### Note:

The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>GRDVKH</sub> symbolizes GMII receive timing (GR) with respect to the time data input signals (D) reaching the valid state (V) relative to the t<sub>RX</sub> clock reference (K) going to the high state (H) or setup time. Also, t<sub>GRDXKL</sub> symbolizes GMII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the t<sub>GRX</sub> clock reference (K) going to the low (L) state or hold time. In general, the clock reference symbol is based on three letters representing the clock of a particular function. For example, the subscript of t<sub>GRX</sub> represents the GMII (G) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub>

Figure 10 shows the GMII receive AC timing diagram.



## 8.2.2 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

## 8.2.2.1 MII Transmit AC Timing Specifications

Table 27 provides the MII transmit AC timing specifications.

Table 27. MII Transmit AC Tim	ing Specifications
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At recommended operating conditions with LV_{DD}/OV_{DD} of 3.3 V ± 10%.
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Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Max	Unit
TX_CLK clock period 10 Mbps	t <sub>MTX</sub>	—	400	—	ns
TX_CLK clock period 100 Mbps	t <sub>MTX</sub>	—	40	—	ns
TX_CLK duty cycle	t <sub>MTXH</sub> /t <sub>MTX</sub>	35	—	65	%
TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay	t <sub>MTKHDX</sub>	1	5	15	ns

#### Ethernet: Three-Speed Ethernet, MII Management

### Table 27. MII Transmit AC Timing Specifications (continued)

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V  $\pm$  10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
TX_CLK data clock rise (20%-80%)	t <sub>MTXR</sub>	1.0	_	4.0	ns
TX_CLK data clock fall (80%–20%)	t <sub>MTXF</sub>	1.0		4.0	ns

### Note:

The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t<sub>MTKHDX</sub> symbolizes MII transmit timing (MT) for the time t<sub>MTX</sub> clock reference (K) going high (H) until data outputs (D) are invalid (X). In general, the clock reference symbol is based on two to three letters representing the clock of a particular function. For example, the subscript of t<sub>MTX</sub> represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub></sub>

Figure 11 shows the MII transmit AC timing diagram.



Figure 11. MII Transmit AC Timing Diagram

## 8.2.2.2 MII Receive AC Timing Specifications

Table 28 provides the MII receive AC timing specifications.

## Table 28. MII Receive AC Timing Specifications

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V ± 10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
RX_CLK clock period 10 Mbps	t <sub>MRX</sub>	—	400	—	ns
RX_CLK clock period 100 Mbps	t <sub>MRX</sub>	—	40	—	ns
RX_CLK duty cycle	t <sub>MRXH</sub> /t <sub>MRX</sub>	35	_	65	%
RXD[3:0], RX_DV, RX_ER setup time to RX_CLK	t <sub>MRDVKH</sub>	10.0	_	—	ns
RXD[3:0], RX_DV, RX_ER hold time to RX_CLK	t <sub>MRDXKH</sub>	10.0	_		ns

# 8.2.3.1 TBI Transmit AC Timing Specifications

Table 29 provides the TBI transmit AC timing specifications.

## Table 29. TBI Transmit AC Timing Specifications

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V ± 10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
GTX_CLK clock period	t <sub>TTX</sub>	_	8.0	—	ns
GTX_CLK duty cycle	t <sub>TTXH</sub> /t <sub>TTX</sub>	40	_	60	%
GTX_CLK to TBI data TXD[7:0], TX_ER, TX_EN delay	t <sub>TTKHDX</sub>	1.0	_	5.0	ns
GTX_CLK clock rise (20%–80%)	t <sub>TTXR</sub>	—	_	1.0	ns
GTX_CLK clock fall time (80%–20%)	t <sub>TTXF</sub>	—		1.0	ns

### Notes:

1. The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>TTKHDV</sub> symbolizes the TBI transmit timing (TT) with respect to the time from t<sub>TTX</sub> (K) going high (H) until the referenced data signals (D) reach the valid state (V) or setup time. Also, t<sub>TTKHDX</sub> symbolizes the TBI transmit timing (TT) with respect to the time from t<sub>TTX</sub> (K) going high (H) until the referenced data signals (D) reach the valid state (V) or setup time. Also, t<sub>TTKHDX</sub> symbolizes the TBI transmit timing (TT) with respect to the time from t<sub>TTX</sub> (K) going high (H) until the referenced data signals (D) reach the invalid state (X) or hold time. In general, the clock reference symbol is based on three letters representing the clock of a particular function. For example, the subscript of t<sub>TTX</sub> represents the TBI (T) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).</sub>

## Figure 14 shows the TBI transmit AC timing diagram.



Figure 14. TBI Transmit AC Timing Diagram

## 8.2.3.2 TBI Receive AC Timing Specifications

Table 30 provides the TBI receive AC timing specifications.

## Table 30. TBI Receive AC Timing Specifications

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V ± 10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Max	Unit
PMA_RX_CLK clock period	t <sub>TRX</sub>		16.0		ns
PMA_RX_CLK skew	t <sub>SKTRX</sub>	7.5	—	8.5	ns
RX_CLK duty cycle	t <sub>TRXH</sub> /t <sub>TRX</sub>	40	_	60	%

# 8.2.4 RGMII and RTBI AC Timing Specifications

Table 31 presents the RGMII and RTBI AC timing specifications.

## Table 31. RGMII and RTBI AC Timing Specifications

At recommended operating conditions with LV<sub>DD</sub> of 2.5 V  $\pm$  5%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Max	Unit
Data to clock output skew (at transmitter)	t <sub>SKRGT</sub>	-0.5	—	0.5	ns
Data to clock input skew (at receiver) <sup>2</sup>	t <sub>SKRGT</sub>	1.0	—	2.8	ns
Clock cycle duration <sup>3</sup>	t <sub>RGT</sub>	7.2	8.0	8.8	ns
Duty cycle for 1000Base-T <sup>4, 5</sup>	t <sub>RGTH</sub> /t <sub>RGT</sub>	45	50	55	%
Duty cycle for 10BASE-T and 100BASE-TX <sup>3, 5</sup>	t <sub>RGTH</sub> /t <sub>RGT</sub>	40	50	60	%
Rise time (20%–80%)	t <sub>RGTR</sub>	—	—	0.75	ns
Fall time (80%–20%)	t <sub>RGTF</sub>	—	—	0.75	ns

Notes:

1. In general, the clock reference symbol for this section is based on the symbols RGT to represent RGMII and RTBI timing. For example, the subscript of t<sub>RGT</sub> represents the TBI (T) receive (RX) clock. Also, the notation for rise (R) and fall (F) times follows the clock symbol. For symbols representing skews, the subscript is SK followed by the clock being skewed (RGT).

2. This implies that PC board design requires clocks to be routed so that an additional trace delay of greater than 1.5 ns is added to the associated clock signal.

3. For 10 and 100 Mbps,  $t_{RGT}$  scales to 400 ns  $\pm$  40 ns and 40 ns  $\pm$  4 ns, respectively.

4. Duty cycle may be stretched/shrunk during speed changes or while transitioning to a received packet clock domains as long as the minimum duty cycle is not violated and stretching occurs for no more than three t<sub>RGT</sub> of the lowest speed transitioned.

5. Duty cycle reference is  $LV_{DD}/2$ .

### Table 34. MII Management AC Timing Specifications (continued)

At recommended operating conditions with  $LV_{DD}$  is 3.3 V ± 10% or 2.5 V ± 5%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Max	Unit	Notes
MDC fall time	t <sub>MDHF</sub>	_	_	10	ns	

#### Notes:

The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>MDKHDX</sub> symbolizes management data timing (MD) for the time t<sub>MDC</sub> from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t<sub>MDDVKH</sub> symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t<sub>MDC</sub> clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub>

- 2. This parameter is dependent on the csb\_clk speed (that is, for a csb\_clk of 267 MHz, the maximum frequency is 8.3 MHz and the minimum frequency is 1.2 MHz; for a csb\_clk of 375 MHz, the maximum frequency is 11.7 MHz and the minimum frequency is 1.7 MHz).
- 3. This parameter is dependent on the csb\_clk speed (that is, for a csb\_clk of 267 MHz, the delay is 70 ns and for a csb\_clk of 333 MHz, the delay is 58 ns).

### Figure 17 shows the MII management AC timing diagram.



Figure 17. MII Management Interface Timing Diagram

Figure 18 and Figure 19 provide the AC test load and signals for the USB, respectively.



# 10 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface of the MPC8349EA.

# **10.1 Local Bus DC Electrical Characteristics**

Table 37 provides the DC electrical characteristics for the local bus interface.

 Table 37. Local Bus DC Electrical Characteristics

Parameter	Symbol	Min	Мах	Unit
High-level input voltage	V <sub>IH</sub>	2	OV <sub>DD</sub> + 0.3	V
Low-level input voltage	V <sub>IL</sub>	-0.3	0.8	V
Input current	I <sub>IN</sub>	_	±5	μA
High-level output voltage, $I_{OH} = -100 \ \mu A$	V <sub>OH</sub>	OV <sub>DD</sub> - 0.2	_	V
Low-level output voltage, $I_{OL} = 100 \ \mu A$	V <sub>OL</sub>		0.2	V

# **15.2 GPIO AC Timing Specifications**

Table 50 provides the GPIO input and output AC timing specifications.

Table 50	. GPIO	Input AC	Timing	Specifications <sup>1</sup>
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Parameter	Symbol <sup>2</sup>	Min	Unit
GPIO inputs—minimum pulse width	t <sub>PIWID</sub>	20	ns

### Notes:

1. Input specifications are measured from the 50 percent level of the signal to the 50 percent level of the rising edge of CLKIN. Timings are measured at the pin.

2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by external synchronous logic. GPIO inputs must be valid for at least t<sub>PIWID</sub> ns to ensure proper operation.

# 16 IPIC

This section describes the DC and AC electrical specifications for the external interrupt pins.

# 16.1 IPIC DC Electrical Characteristics

Table 51 provides the DC electrical characteristics for the external interrupt pins.

Table 51. IPIC DC	Electrical Characteristics <sup>1</sup>
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Parameter	Symbol	Condition	Min	Max	Unit	Notes
Input high voltage	V <sub>IH</sub>	—	2.0	OV <sub>DD</sub> + 0.3	V	—
Input low voltage	V <sub>IL</sub>	—	-0.3	0.8	V	—
Input current	I <sub>IN</sub>	—	—	±5	μA	—
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 8.0 mA	—	0.5	V	2
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3.2 mA	—	0.4	V	2

### Notes:

1. This table applies for pins  $\overline{IRQ}$ [0:7],  $\overline{IRQ}$ \_OUT, and  $\overline{MCP}$ \_OUT.

2. IRQ\_OUT and MCP\_OUT are open-drain pins; thus VOH is not relevant for those pins.

# **16.2 IPIC AC Timing Specifications**

Table 52 provides the IPIC input and output AC timing specifications.

## Table 52. IPIC Input AC Timing Specifications<sup>1</sup>

Parameter	Symbol <sup>2</sup>	Min	Unit
IPIC inputs—minimum pulse width	t <sub>PICWID</sub>	20	ns

### Notes:

1. Input specifications are measured at the 50 percent level of the IPIC input signals. Timings are measured at the pin.

 IPIC inputs and outputs are asynchronous to any visible clock. IPIC outputs should be synchronized before use by external synchronous logic. IPIC inputs must be valid for at least t<sub>PICWID</sub> ns to ensure proper operation in edge triggered mode.

SPI

# 17 SPI

This section describes the SPI DC and AC electrical specifications.

# 17.1 SPI DC Electrical Characteristics

Table 53 provides the SPI DC electrical characteristics.

## Table 53. SPI DC Electrical Characteristics

Parameter	Symbol	Condition	Min	Мах	Unit
Input high voltage	V <sub>IH</sub>	_	2.0	OV <sub>DD</sub> + 0.3	V
Input low voltage	V <sub>IL</sub>	_	-0.3	0.8	V
Input current	I <sub>IN</sub>	_	—	±5	μA
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -8.0 mA	2.4	—	V
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 8.0 mA	—	0.5	V
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3.2 mA	—	0.4	V

# 17.2 SPI AC Timing Specifications

Table 54 provides the SPI input and output AC timing specifications.

## Table 54. SPI AC Timing Specifications<sup>1</sup>

Parameter	Symbol <sup>2</sup>	Min	Мах	Unit
SPI outputs valid—Master mode (internal clock) delay	t <sub>NIKHOV</sub>	_	6	ns
SPI outputs hold—Master mode (internal clock) delay	t <sub>NIKHOX</sub>	0.5	—	ns
SPI outputs valid—Slave mode (external clock) delay	t <sub>NEKHOV</sub>	_	8	ns
SPI outputs hold—Slave mode (external clock) delay	t <sub>NEKHOX</sub>	2	—	ns
SPI inputs—Master mode (internal clock input setup time	t <sub>NIIVKH</sub>	4	—	ns
SPI inputs—Master mode (internal clock input hold time	t <sub>NIIXKH</sub>	0	—	ns
SPI inputs—Slave mode (external clock) input setup time	t <sub>NEIVKH</sub>	4	—	ns
SPI inputs—Slave mode (external clock) input hold time	t <sub>NEIXKH</sub>	2	—	ns

Notes:

1. Output specifications are measured from the 50 percent level of the rising edge of CLKIN to the 50 percent level of the signal. Timings are measured at the pin.

The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>NIKHOX</sub> symbolizes the internal timing (NI) for the time SPICLK clock reference (K) goes to the high state (H) until outputs (O) are invalid (X).
</sub>

# 18.1 Package Parameters for the MPC8349EA TBGA

The package parameters are provided in the following list. The package type is  $35 \text{ mm} \times 35 \text{ mm}$ , 672 tape ball grid array (TBGA).

Package outline	35 mm × 35 mm
Interconnects	672
Pitch	1.00 mm
Module height (typical)	1.46 mm
Solder balls	62 Sn/36 Pb/2 Ag (ZU package) 96.5 Sn/3.5Ag (VV package)
Ball diameter (typical)	0.64 mm

Package and Pin Listings

### Table 55. MPC8349EA (TBGA) Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
MPH1_PWRFAULT/ DR_RX_ERROR_PWRFAULT	E27	I	OV <sub>DD</sub>	
MPH1_PCTL0/DR_TX_VALID_PCTL0	A29	0	OV <sub>DD</sub>	—
MPH1_PCTL1/DR_TX_VALIDH_PCTL1	D28	0	OV <sub>DD</sub>	—
MPH1_CLK/DR_CLK	B29	I	OV <sub>DD</sub>	—
	USB Port 0			
MPH0_D0_ENABLEN/ DR_D8_CHGVBUS	C29	I/O	OV <sub>DD</sub>	—
MPH0_D1_SER_TXD/ DR_D9_DCHGVBUS	A30	I/O	OV <sub>DD</sub>	—
MPH0_D2_VMO_SE0/DR_D10_DPPD	E28	I/O	OV <sub>DD</sub>	_
MPH0_D3_SPEED/DR_D11_DMMD	B30	I/O	OV <sub>DD</sub>	_
MPH0_D4_DP/DR_D12_VBUS_VLD	C30	I/O	OV <sub>DD</sub>	—
MPH0_D5_DM/DR_D13_SESS_END	A31	I/O	OV <sub>DD</sub>	—
MPH0_D6_SER_RCV/DR_D14	B31	I/O	OV <sub>DD</sub>	—
MPH0_D7_DRVVBUS/ DR_D15_IDPULLUP	C31	I/O	OV <sub>DD</sub>	—
MPH0_NXT/DR_RX_ACTIVE_ID	B32		OV <sub>DD</sub>	—
MPH0_DIR_DPPULLUP/DR_RESET	A32	I/O	OV <sub>DD</sub>	—
MPH0_STP_SUSPEND/ DR_TX_READY	A33	I/O	OV <sub>DD</sub>	—
MPH0_PWRFAULT/DR_RX_VALIDH	C32	I	OV <sub>DD</sub>	—
MPH0_PCTL0/DR_LINE_STATE0	D31	I/O	OV <sub>DD</sub>	—
MPH0_PCTL1/DR_LINE_STATE1	E30	I/O	OV <sub>DD</sub>	_
MPH0_CLK/DR_RX_VALID	B33	I	OV <sub>DD</sub>	—
	Programmable Interrupt Controller			
MCP_OUT	AN33	0	OV <sub>DD</sub>	2
IRQ0/MCP_IN/GPIO2[12]	C19	I/O	OV <sub>DD</sub>	—
IRQ[1:5]/GPIO2[13:17]	C22, A22, D21, C21, B21	I/O	OV <sub>DD</sub>	—
IRQ[6]/GPIO2[18]/CKSTOP_OUT	A21	I/O	OV <sub>DD</sub>	—
IRQ[7]/GPIO2[19]/CKSTOP_IN	C20	I/O	OV <sub>DD</sub>	
	Ethernet Management Interface			
EC_MDC	A7	0	LV <sub>DD1</sub>	
EC_MDIO	E9	I/O	LV <sub>DD1</sub>	11

Package and Pin Listings

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GND	A1, A34, C1, C7, C10, C11, C15, C23, C25, C28, D1, D8, D20, D30, E7, E13, E15, E17, E18, E21, E23, E25, E32, F6, F19, F27, F30, F34, G31, H5, J4, J34, K30, L5, M2, M5, M30, M33, N3, N5, P30, R5, R32, T5, T30, U6, U29, U33, V2, V5, V30, W6, W30, Y30, AA2, AA30, AB2, AB6, AB30, AC3, AC6, AD31, AE5, AF2, AF5, AF31, AG30, AG31, AH4, AJ3, AJ19, AJ22, AK7, AK13, AK14, AK16, AK18, AK20, AK25, AK28, AL3, AL5, AL10, AL12, AL22, AL27, AM1, AM6, AM7, AN12, AN17, AN34, AP1, AP8, AP34	_	_	_
GV <sub>DD</sub>	A2, E2, G5, G6, J5, K4, K5, L4, N4, P5, R6, T6, U5, V1, W5, Y5, AA4, AB3, AC4, AD5, AF3, AG5, AH2, AH5, AH6, AJ6, AK6, AK8, AK9, AL6	Power for DDR DRAM I/O voltage (2.5 V)	GV <sub>DD</sub>	_
LV <sub>DD1</sub>	C9, D11	Power for three speed Ethernet #1 and for Ethernet management interface I/O (2.5 V, 3.3 V)	LV <sub>DD1</sub>	_
LV <sub>DD2</sub>	C6, D9	Power for three speed Ethernet #2 I/O (2.5 V, 3.3 V)	LV <sub>DD2</sub>	_
V <sub>DD</sub>	E19, E29, F7, F9, F11,F13, F15, F17, F18, F21, F23, F25, F29, H29, J6, K29, M29, N6, P29, T29, U30, V6, V29, W29, AB29, AC5, AD29, AF6, AF29, AH29, AJ8, AJ12, AJ14, AJ16, AJ18, AJ20, AJ21, AJ23, AJ25, AJ26, AJ27, AJ28, AJ29, AK10	Power for core (1.2 V nominal, 1.3 V for 667 MHz)	V <sub>DD</sub>	_
OV <sub>DD</sub>	B22, B28, C16, C17, C24, C26, D13, D15, D19, D29, E31, F28, G33, H30, L29, L32, N32, P31, R31, U32, W31, Y29, AA29, AC30, AE31, AF30, AG29, AJ17, AJ30, AK11, AL15, AL19, AL21, AL29, AL30, AM20, AM23, AM24, AM26, AM28, AN11, AN13	PCI, 10/100 Ethernet, and other standard (3.3 V)	OV <sub>DD</sub>	_
MVREF1	МЗ	I	DDR reference voltage	_

## Table 55. MPC8349EA (TBGA) Pinout Listing (continued)

As shown in Figure 41, the primary clock input (frequency) is multiplied up by the system phase-locked loop (PLL) and the clock unit to create the coherent system bus clock ( $csb\_clk$ ), the internal clock for the DDR controller ( $ddr\_clk$ ), and the internal clock for the local bus interface unit ( $lbiu\_clk$ ).

The *csb\_clk* frequency is derived from a complex set of factors that can be simplified into the following equation:

 $csb\_clk = \{PCI\_SYNC\_IN \times (1 + CFG\_CLKIN\_DIV)\} \times SPMF$ 

In PCI host mode, PCI\_SYNC\_IN  $\times$  (1 + CFG\_CLKIN\_DIV) is the CLKIN frequency.

The *csb\_clk* serves as the clock input to the e300 core. A second PLL inside the e300 core multiplies the *csb\_clk* frequency to create the internal clock for the e300 core (*core\_clk*). The system and core PLL multipliers are selected by the SPMF and COREPLL fields in the reset configuration word low (RCWL), which is loaded at power-on reset or by one of the hard-coded reset options. See the chapter on reset, clocking, and initialization in the *MPC8349EA Reference Manual* for more information on the clock subsystem.

The internal *ddr\_clk* frequency is determined by the following equation:

 $ddr_clk = csb_clk \times (1 + RCWL[DDRCM])$ 

 $ddr_clk$  is not the external memory bus frequency;  $ddr_clk$  passes through the DDR clock divider (÷2) to create the differential DDR memory bus clock outputs (MCK and  $\overline{\text{MCK}}$ ). However, the data rate is the same frequency as  $ddr_clk$ .

The internal *lbiu\_clk* frequency is determined by the following equation:

 $lbiu_clk = csb_clk \times (1 + RCWL[LBIUCM])$ 

*lbiu\_clk* is not the external local bus frequency; *lbiu\_clk* passes through the LBIU clock divider to create the external local bus clock outputs (LSYNC\_OUT and LCLK[0:2]). The LBIU clock divider ratio is controlled by LCCR[CLKDIV].

In addition, some of the internal units may have to be shut off or operate at lower frequency than the *csb\_clk* frequency. Those units have a default clock ratio that can be configured by a memory-mapped register after the device exits reset. Table 56 specifies which units have a configurable clock frequency.

Unit	Default Frequency	Options
TSEC1	csb_clk/3	Off, csb_clk, csb_clk/2, csb_clk/3
TSEC2, I <sup>2</sup> C1	csb_clk/3	Off, csb_clk, csb_clk/2, csb_clk/3
Security core	csb_clk/3	Off, <i>csb_clk,</i> csb_clk/2, <i>csb_clk/3</i>
USB DR, USB MPH	csb_clk/3	Off, csb_clk, csb_clk/2, <i>csb_clk/3</i>
PCI1, PCI2 and DMA complex	csb_clk	Off, csb_clk

			Input Clock Frequency (MHz) <sup>2</sup>					
CFG_CLKIN_DIV at Reset <sup>1</sup>	SPMF	<i>csb_clk</i> : Input Clock Ratio <sup>2</sup>	16.67	25	33.33	66.67		
			<i>csb_clk</i> Frequency (MHz)					
Low	0110	6 : 1	100	150	200			
Low	0111	7 : 1	116	175	233			
Low	1000	8 : 1	133	200	266			
Low	1001	9 : 1	150	225	300			
Low	1010	10 : 1	166	250	333			
Low	1011	11 : 1	183	275				
Low	1100	12 : 1	200	300				
Low	1101	13 : 1	216	325				
Low	1110	14 : 1	233					
Low	1111	15 : 1	250					
Low	0000	16 : 1	266					
High	0010	4 : 1		100	133	266		
High	0011	6 : 1	100	150	200			
High	0100	8:1	133	200	266			
High	0101	10 : 1	166	250	333			
High	0110	12 : 1	200	300				
High	0111	14 : 1	233					
High	1000	16 : 1	266					

Table 60. CSB Frequency Options for Agent Mode (continued)

<sup>1</sup> CFG\_CLKIN\_DIV doubles csb\_clk if set high.

<sup>2</sup> CLKIN is the input clock in host mode; PCI\_CLK is the input clock in agent mode.

# 19.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb\_clk*) and the e300 core clock (*core\_clk*). Table 61 shows the encodings for RCWL[COREPLL]. COREPLL values that are not listed in Table 61 should be considered as reserved.

## NOTE

Core VCO frequency = core frequency × VCO divider

VCO divider must be set properly so that the core VCO frequency is in the range of 800–1800 MHz.

# **19.3 Suggested PLL Configurations**

Table 62 shows suggested PLL configurations for 33 and 66 MHz input clocks.

Table 62.	Suggested	<b>PLL Configurations</b>
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	RC	WL	40	0 MHz Dev	ice	53	3 MHz Dev	ice	667 MHz De		vice	
Ref No. <sup>1</sup>	SPMF	CORE PLL	Input Clock Freq (MHz) <sup>2</sup>	CSB Freq (MHz)	Core Freq (MHz)	Input Clock Freq (MHz) <sup>2</sup>	CSB Freq (MHz)	Core Freq (MHz)	Input Clock Freq (MHz) <sup>2</sup>	CSB Freq (MHz)	Core Freq (MHz)	
33 MHz CLKIN/PCI_CLK Options												
922	1001	0100010	—	—	—	—	—	f300	33	300	300	
723	0111	0100011	33	233	350	33	233	350	33	233	350	
604	0110	0000100	33	200	400	33	200	400	33	200	400	
624	0110	0100100	33	200	400	33	200	400	33	200	400	
803	1000	0000011	33	266	400	33	266	400	33	266	400	
823	1000	0100011	33	266	400	33	266	400	33	266	400	
903	1001	0000011	<b>_</b>			33	300	450	33	300	450	
923	1001	0100011	—			33	300	450	33	300	450	
704	0111	0000011	_			33	233	466	33	233	466	
724	0111	0100011	_			33	233	466	33	233	466	
A03	1010	0000011				33	333	500	33	333	500	
804	1000	0000100	—			33	266	533	33	266	533	
705	0111	0000101		_			_		33	233	583	
606	0110	0000110		_			_		33	200	600	
904	1001	0000100		_			—			300	600	
805	1000	0000101					_			266	667	
A04	1010	0000100		—			—		33	333	667	
				66 N	/Hz CLKIN	/PCI_CLK	Options					
304	0011	0000100	66	200	400	66	200	400	66	200	400	
324	0011	0100100	66	200	400	66	200	400	66	200	400	
403	0100	0000011	66	266	400	66	266	400	66	266	400	
423	0100	0100011	66	266	400	66	266	400	66	266	400	
305	0011	0000101				66	200	500	66	200	500	
503	0101	0000011		_		66	333	500	66	333	500	
404	0100	0000100		_			266	533	66	266	533	

## Table 63. Package Thermal Characteristics for TBGA (continued)

Characteristic	Symbol	Value	Unit	Notes
Junction-to-package natural convection on top	$\Psi_{JT}$	1	°C/W	6

Notes:

- 1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 2. Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board horizontal.
- 3. Per JEDEC JESD51-6 with the board horizontal, 1 m/s is approximately equal to 200 linear feet per minute (LFM).
- 4. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- 5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
- 6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

# 20.2 Thermal Management Information

For the following sections,  $P_D = (V_{DD} \times I_{DD}) + P_{I/O}$  where  $P_{I/O}$  is the power dissipation of the I/O drivers. See Table 5 for I/O power dissipation values.

# 20.2.1 Estimation of Junction Temperature with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T<sub>J</sub>, can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

 $T_J$  = junction temperature (°C)

 $T_A$  = ambient temperature for the package (°C)

 $R_{\theta JA}$  = junction-to-ambient thermal resistance (°C/W)

 $P_D$  = power dissipation in the package (W)

The junction-to-ambient thermal resistance is an industry-standard value that provides a quick and easy estimation of thermal performance. Generally, the value obtained on a single-layer board is appropriate for a tightly packed printed-circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated. Test cases have demonstrated that errors of a factor of two (in the quantity  $T_J - T_A$ ) are possible.

## 20.2.2 Estimation of Junction Temperature with Junction-to-Board Thermal Resistance

The thermal performance of a device cannot be adequately predicted from the junction-to-ambient thermal resistance. The thermal performance of any component is strongly dependent on the power dissipation of surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter

have a low ESR (equivalent series resistance) rating to ensure the quick response time. They should also be connected to the power and ground planes through two vias to minimize inductance. Suggested bulk capacitors are 100–330  $\mu$ F (AVX TPS tantalum or Sanyo OSCON).

# 21.4 Connection Recommendations

To ensure reliable operation, connect unused inputs to an appropriate signal level. Unused active low inputs should be tied to  $OV_{DD}$ ,  $GV_{DD}$ , or  $LV_{DD}$  as required. Unused active high inputs should be connected to GND. All NC (no-connect) signals must remain unconnected.

Power and ground connections must be made to all external  $V_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $OV_{DD}$ , and GND pins of the MPC8349EA.

# 21.5 Output Buffer DC Impedance

The MPC8349EA drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for  $I^2C$ ).

To measure  $Z_0$  for the single-ended drivers, an external resistor is connected from the chip pad to  $OV_{DD}$  or GND. Then the value of each resistor is varied until the pad voltage is  $OV_{DD}/2$  (see Figure 43). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open) and  $R_P$  is trimmed until the voltage at the pad equals  $OV_{DD}/2$ .  $R_P$  then becomes the resistance of the pull-up devices.  $R_P$  and  $R_N$  are designed to be close to each other in value. Then,  $Z_0 = (R_P + R_N) \div 2$ .



Figure 43. Driver Impedance Measurement

Two measurements give the value of this resistance and the strength of the driver current source. First, the output voltage is measured while driving logic 1 without an external differential termination resistor. The measured voltage is  $V_1 = R_{source} \times I_{source}$ . Second, the output voltage is measured while driving logic 1 with an external precision differential termination resistor of value  $R_{term}$ . The measured voltage is